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<u>Examiner Initial*</u>	<u>Document Number</u>	<u>Issue Date</u>	<u>Name</u>
____ 1	6,104,047	08/15/2000	Watanabe

Foreign Patent Documents

<u>Examiner Initial*</u>	<u>Document Number</u>	<u>Publication Date</u>	<u>Country or Patent Office</u>	<u>Translation</u>
____ 2	2000-022197	01/21/2000	Japan	No
____ 3	61-198688	09/03/1986	Japan	No
____ 4	2004-031707	01/29/2004	Japan	No

Other Documents

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____ 5 Y. Muramoto et al., *InP/InGaAs Pin Photodiode Structure Maximising Bandwidth and Efficiency*, Electronics Letters, Vol. 39, No. 24, November 27, 2003, pp. 1749-1750.

Examiner: /Tifney Skyles/ (04/08/2009)

Date Considered:

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609, draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /T.S./